## HAMAMATSU

PHOTON IS OUR BUSINESS

# **MEMS-FPI** spectrum sensor



C13272-03

# Ultra-compact near infrared spectrum sensor that integrates MEMS-FPI tunable filter and photosensor

The MEMS-FPI spectrum sensor S13272-03 is a ultra-compact sensor that houses a MEMS-FPI (Fabry-Perot Interferometer) tunable filter that can vary its transmission wavelength depending on the applied voltage and InGaAs PIN photodiode in a single package. The spectral response range is 1550 to 1850 nm. It is suitable for installation in simple, compact instruments for measuring material absorbance and the like.

#### Features

- **Built-in Hamamatsu InGaAs PIN photodiode single** element chip
- Spectral response range: 1550 to 1850 nm
- **■** Ultra-compact: TO-5 package
- Ultra light: 1 g
- → Hermetically sealed package: High reliability in high humidity environment
- **■** Built-in thermistor
- Built-in band-pass filter for cutting off wavelengths outside the spectral response range

#### Applications

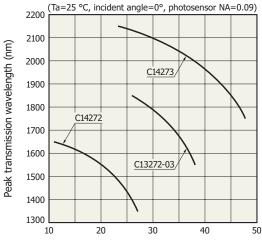
- → Screening of plastic, solutions, and the like
- **■** Installation into mobile measuring devices

#### **ـ** Lineup of MEMS-FPI spectrum sensors

Type no.	Spectral response range Typ. (nm)	Spectral resolution (FWHM) Max. (nm)
C14272*1	1350 to 1650	18
C13272-03	1550 to 1850	20
C14273* <sup>2</sup>	1750 to 2150	22

<sup>\*1:</sup> See datasheet C14272

■ Peak transmission wavelength vs. filter control voltage (typical example)



Filter control voltage (V)

<sup>\*2:</sup> See datasheet C14273

#### **♣** Absolute maximum ratings (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Value	Unit
Filter control voltage*3	-		Vλ1550nm + 0.5	V
Photosensor reverse voltage	VR		1	V
Photosensor forward current	IF		10	mA
Operating temperature*4	Topr		-40 to +85	°C
Storage temperature*4	Tstg		-40 to +125	°C
Recommended soldering conditions	-		260 °C or less, within 10 s	-
		Terminals other than photosensor terminals	500	
Electrostatic withstand voltage*5	-	Between the anode and cathode of the photosensor	100	V(HBM)*6

<sup>\*3:</sup> Applying a voltage that is +0.5 V or higher than V $\lambda$ 1550nm (filter control voltage to transmit light at  $\lambda$ =1550 nm) at a specific temperature may damage the MEMS-FPI tunable filter. For V $\lambda$ 1550nm of individual products at Ta=25°C, see the final inspection sheet.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

#### **E**lectrical and optical characteristics of MEMS-FPI spectrum sensor (Ta=25 °C, unless otherwise noted)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Spectral response range	λ		1550 to 1850		nm
Spectral resolution (FWHM)*7	-	-	-	20	nm
Wavelength temperature dependence*8	-	-	0.4	-	nm/°C
Wavelength reproducibility*9	-	-	±2	-	nm
Settling time (0 V $\rightarrow$ V $\lambda$ 1550nm)*10	-	-	1	-	ms
Dark current*11	ID	-	10	100	nA
Thermistor resistance	_	9.6	10	10.4	kΩ

<sup>\*7:</sup> Incident angle=0°, photosensor NA=0.09

#### **■** Electrical and optical characteristics of built-in InGaAs PIN photodiode (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Photosensitive area	Α			ф0.3		mm
Spectral response range	λ			900 to 2100		nm
Peak sensitivity wavelength	λр		1850	1950	2050	nm
Photosensitivity	S	λ=λρ	1.0	1.2	-	A/W
Detectivity	D*	λ=λρ	$1 \times 10^{11}$	$3.5 \times 10^{11}$	-	cm·Hz <sup>1/2</sup> /W
Noise equivalent power	NEP	λ=λρ	-	$6.5 \times 10^{-14}$	2 × 10 <sup>-13</sup>	W/Hz <sup>1/2</sup>
Terminal capacitance	Ct	VR=0 V, f=1 MHz	-	30	55	pF



<sup>\*4:</sup> No condensation

When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

<sup>\*5:</sup> This product is an electrostatic sensitive device. When handling the product, precautions need to be taken to avoid damage and deterioration due to static electricity. For details, refer to the instruction manual supplied with the product.

<sup>\*6:</sup> Human body model

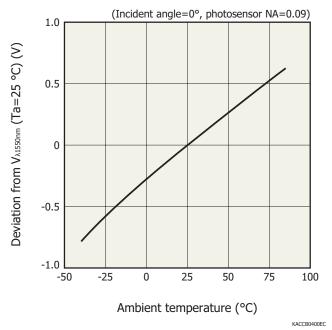
<sup>\*8:</sup> λ=1700 nm

<sup>\*9:</sup> When filter control voltage, incident light condition, and usage environment, etc. are constant

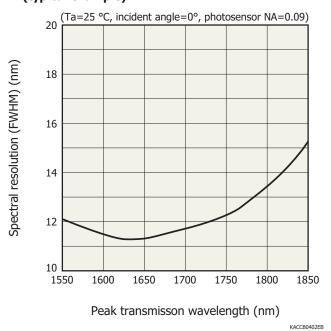
<sup>\*10:</sup> Time for the output signal to reach 99% of the stable signal level when the control voltage of the MEMS-FPI tunable filter is varied from 0 V to Vλ1550nm

<sup>\*11:</sup> VR=0.5 V

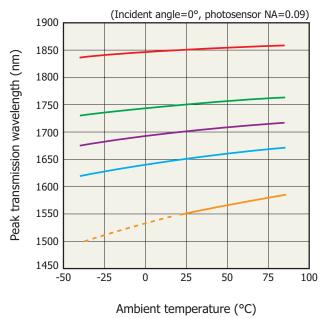
#### Temperature characteristics of VA1550nm (typical example)

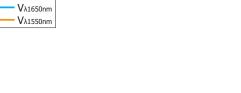


#### Spectral resolution vs. peak transmisson wavelength (typical example)



#### Peak transmission wavelength vs. ambient temperature (typical example)





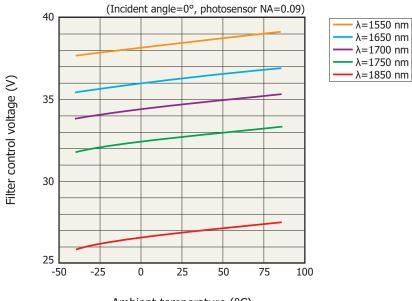
The broken line corresponds to data when the built-in band-pass filter is removed. The C13272-03 cannot detect the peak transmission wavelength accurately in this range. This is because when the ambient temperature is less than 25 °C, the peak transmission wavelength of the MEMS-FPI tunable filter is outside the transmission wavelength range of the band-pass filter.

KACCB0403EC

V<sub>λ1850nm</sub> V<sub>λ1750nm</sub>

**V**λ1700nm

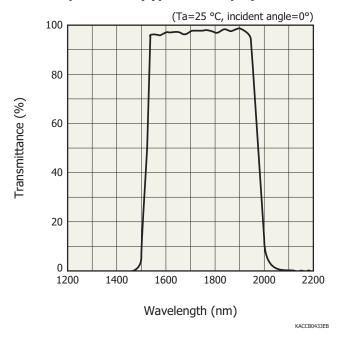
#### Filter control voltage vs. ambient temperature (typical example)



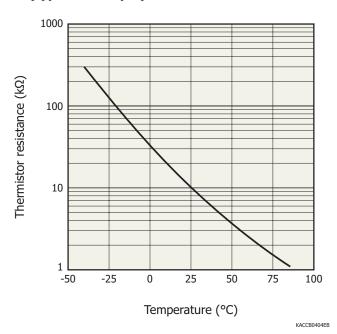
Ambient temperature (°C)

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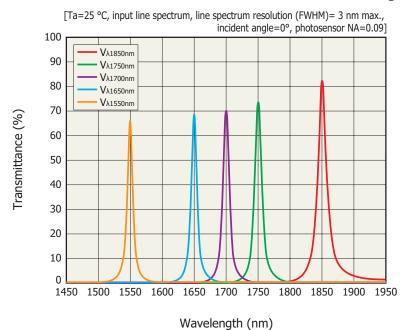
#### Spectral transmittance characteristics of band-pass filter (typical example)



# Thermistor resistance vs.temperature (typical example)



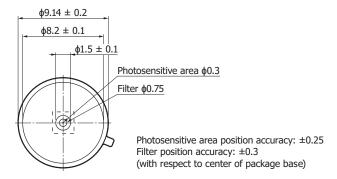
#### **Transmittance of MEMS-FPI tunable filter vs. wavelength (typical example)**

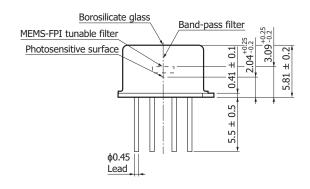


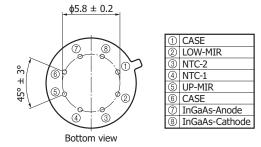
• There is tolerance in filter control voltage for arbitrary peak transmission wavelength from unit to unit. The individual data for V\(\lambda\)1850nm and V\(\lambda\)1550nm at Ta=25 °C is to be described in an inspection sheet attached with a product on delivery.

EA

#### Dimensional outline (unit: mm)







KACCA0450EA

#### **₽** Pin connections

Pin no.	Name	Input/Output	Description
1	CASE	-	Case connection
2	LOW-MIR	Input	MEMS-FPI tunable filter lower electrode
3	NTC-2	Output	For thermistor
4	NTC-1	Output	For thermistor
5	UP-MIR	Input	MEMS-FPI tunable filter upper electrode
6	CASE	-	Case connection
7	InGaAs-Anode	Output	
8	InGaAs-Cathode	Output	

#### **■** Marking information

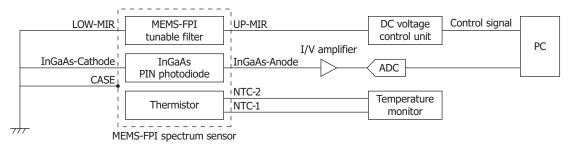
Marking item	Description		
DataMatrix	Shape: rectangle Cell size: 0.14 × 0.14 mm Symbol size: 12 × 26 cell Input information example: C13272-03, **##### ("Type no." + "," + "Serial no.")		
C13272-03	Type no.		
**####	Serial no.  **: information on year and month  #####: number of five digits (number of individual product)		

Note: KEYENCE CORPORATION code reader SR-1000 is recommended for reading the DataMatrix.

# DataMatrix Type no. Serial no.

KACCC1026EA

#### **-** Connection example

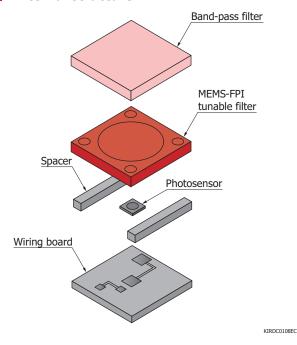


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#### MEMS-FPI spectrum sensor structure

The MEMS-FPI spectrum sensor is composed of a MEMS-FPI tunable filter, photosensor (photodiode), and the like. It has a simple structure in which a MEMS-FPI tunable filter and photosensor is arranged on the same axis as the direction of the incident light. Though this product is a spectrum sensor, it uses a single-element photosensor and does not require an expensive multichannel photosensor.

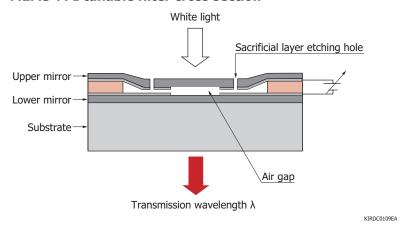
#### Internal structure



#### MEMS-FPI tunable filter

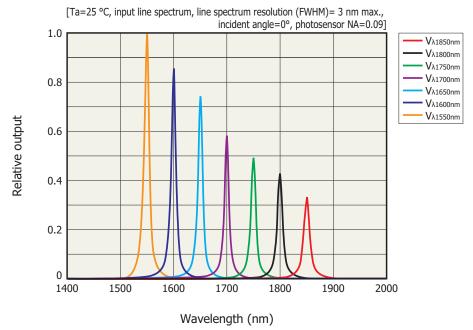
The MEMS-FPI tunable filter has an upper mirror and a lower mirror that are placed opposite each other with an air gap in between them. When a voltage is applied across the mirrors, an electrostatic attractive force is produced to adjust the air gap. To facilitate this action, the upper mirror has a membrane (thin film) structure. If the air gap is  $m\lambda/2$  (m: integer), it functions as a filter that allows wavelengths near  $\lambda$  to pass through. When the filter control voltage is increased, the air gap is narrowed by the electrostatic attractive force, and the transmission peak wavelength shifts to the short-wavelength side.

#### **► MEMS-FPI** tunable filter cross section





#### Spectral response (typical example)



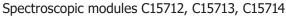
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#### Precautions

Note the following when handling the product and also after installing into a device.

- Handling
- · When touching the product, it is recommended to wear gloves or use tweezers. Touching the product with bare hands may cause degradation in characteristics and plating corrosion and may lead to problems with solder wettability.
- · Perform work in a clean place.
- Filter control voltage
- · Apply filter control voltage as defined by the absolute maximum ratings. Applying a filter control voltage exceeding the absolute maximum ratings may damage the MEMS-FPI tunable filter.
- Static electricity
- The MEMS-FPI spectrum sensor is an electrostatic sensitive device. When handling the product, precautions need to be taken to avoid damage and deterioration due to static electricity. For details, refer to the instruction manual supplied with the product.

#### Related product





These are compact modules with built-in MEMS-FPI spectroscopic sensors, light sources, and control circuits. Since they come with evaluation software that has functions such as setting measurement conditions, data acquisition and storage, and graph display, spectrum and absorbance can be easily measured by connecting to a PC via USB. It can also be used to characterize MEMS-FPI spectroscopic sensors C14272, C13272-03, and C14273.

Type no.	Built-in MEMS-FPI spectrum sensor	Spectral response range
C15712	C14272	1350 to 1650 nm
C15713	C13272-03	1550 to 1850 nm
C15714	C14273	1750 to 2150 nm

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- · Safety consideration
- Compound opto-semiconductors (photosensors, light emitters)
- Technical information
- MEMS-FPI spectrum sensors, spectroscopic modules
- · Compound semiconductor photosensors

Information described in this material is current as of June 2022.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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